

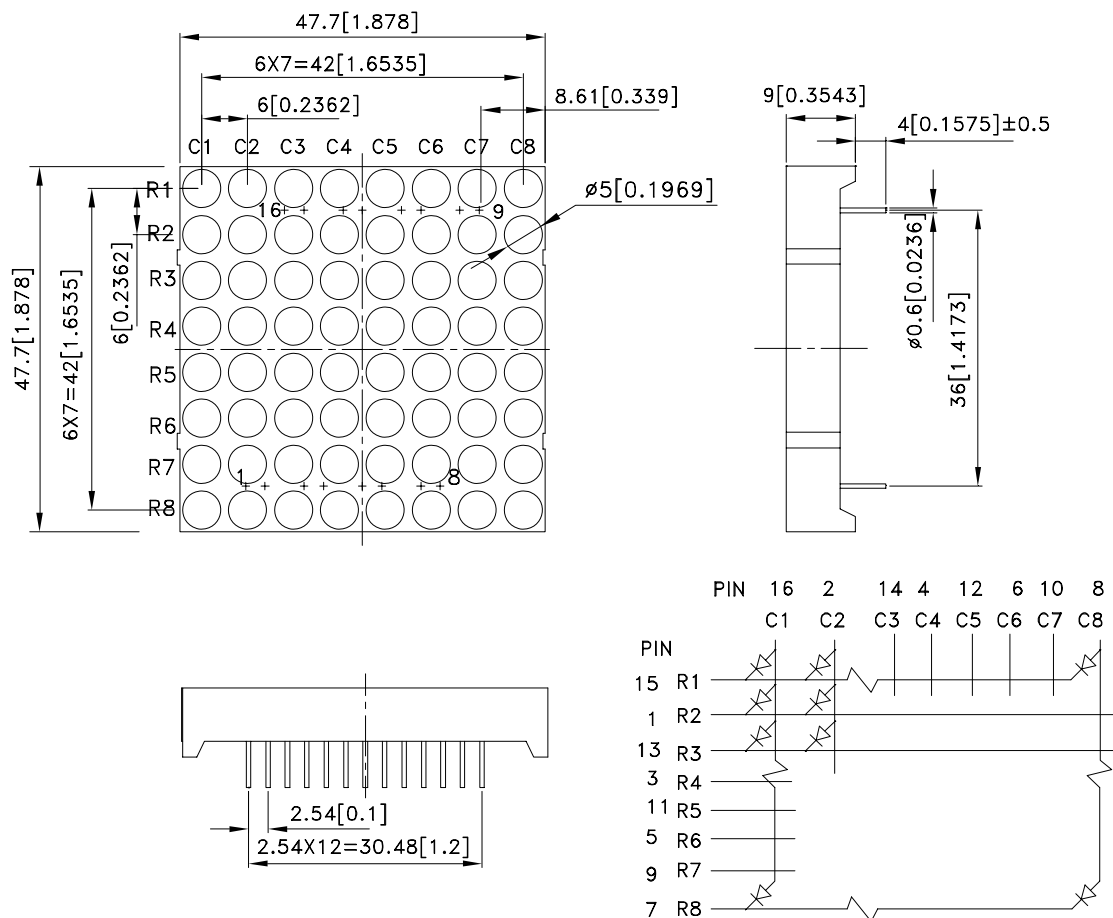
Features

- 1.85 INCH MATRIX HEIGHT.
- DOT SIZE 5mm.
- HIGH CONTRAST AND LIGHT OUTPUT.
- COMPATIBLE WITH ASCII AND EBCDIC CODES.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- CATEGORIZED FOR COLOR.
- MECHANICALLY RUGGED.
- STANDARD: GRAY FACE, WHITE DOT.
- RoHS COMPLIANT.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.



Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
TA18-21EWA	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	4700	19650	Column Anode

Note:

1. Luminous Intensity/ Luminous Flux: +/-15%

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	High Efficiency Red	627		nm	IF=20mA
$\lambda_D[1]$	Dominant Wavelength	High Efficiency Red	625		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red	45		nm	IF=20mA
C	Capacitance	High Efficiency Red	15		pF	VF=0V;f=1MHz
VF[2]	Forward Voltage	High Efficiency Red	2.0	2.5	V	IF=20mA
IR	Reverse Current	High Efficiency Red		10	uA	VR = 5V

Notes:

1.Wavelength: +/-1nm

2.Forward Voltage: +/-0.1V

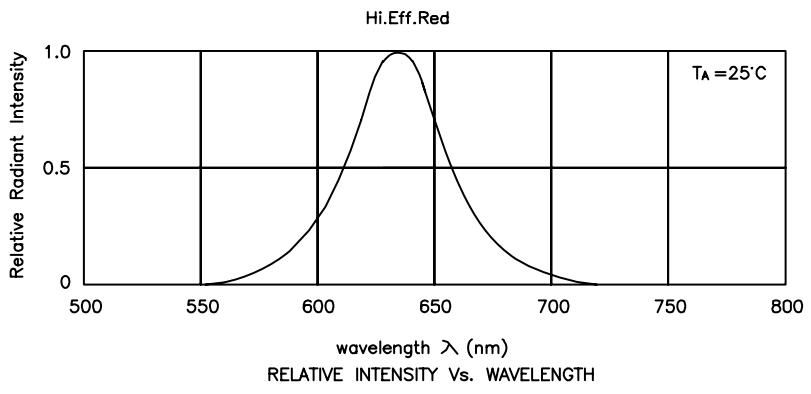
Absolute Maximum Ratings at TA=25°C

Parameter	High Efficiency Red	Units
Power dissipation	75	mW
DC Forward Current	30	mA
Peak Forward Current [1]	160	mA
Reverse Voltage	5	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 3~5 Seconds	

Notes:

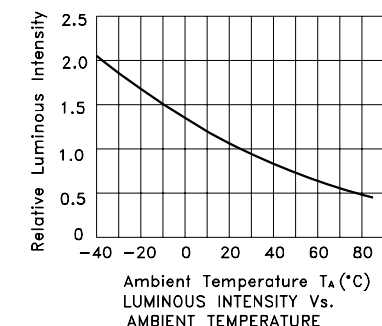
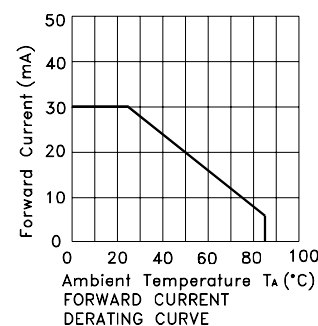
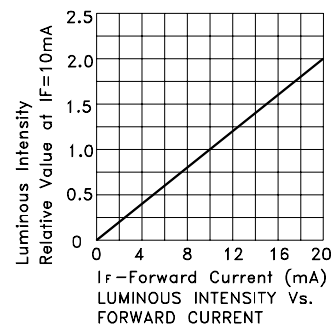
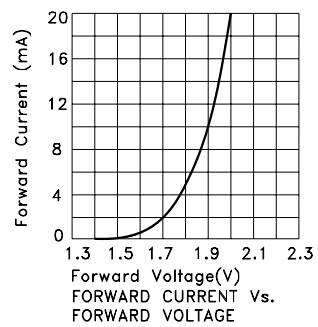
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.



High Efficiency Red

TA18-21EWA



PACKING & LABEL SPECIFICATIONS

TA18-21EWA

